

Application Data Sheet

Inventor Information

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Application Information

Title Line One:

Epitaxial Silicon Wafer

Total Drawing Sheets:

4

Formal Drawings:

Yes

Application Type:

Utility

Docket Number:

86396

Representative Information

Registration Number One:

24,003

Registration Number Two:

22,839

Registration Number Three:

28,903

Registration Number Four:

27,429

Registration Number Five:

25,060

Registration Number Six:

22,053

Registration Number Seven:

27,466

Registration Number Eight 29,434  
Registration Number Nine: 29,054  
Registration Number Ten: 29,381  
Registration Number Eleven: 34,044  
Registration Number Twelve: 27,600  
Registration Number Thirteen: 34,137  
Registration Number Fourteen: 39,724  
Registration Number Fifteen: 37,963  
Registration Number Sixteen: 41,050  
Registration Number Seventeen: 34,217

This application is based on application

Application One: PCT/JP00/04216

Filing Date: June 26, 2000

which is based on priority document

Japanese application no. 241187/1999

Filing Date: August 27, 1999